

# 1N5400 - 1N5408

## Features

- 3.0 ampere operation at  $T_A = 75^\circ\text{C}$  with no thermal runaway.
- High current capability.
- Low leakage.



## General Purpose Rectifiers

### Absolute Maximum Ratings\*

$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Value									Units
		5400	5401	5402	5403	5404	5405	5406	5407	5408	
$V_{RRM}$	Maximum Repetitive Reverse Voltage	50	100	200	300	400	500	600	800	1000	V
$I_{F(AV)}$	Average Rectified Forward Current, .375 " lead length @ $T_A = 75^\circ\text{C}$										A
$I_{FSM}$	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave										A
$T_{stg}$	Storage Temperature Range										$^\circ\text{C}$
$T_J$	Operating Junction Temperature										$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

## Thermal Characteristics

Symbol	Parameter	Value									Units
$P_D$	Power Dissipation	6.25									W
$R_{JA}$	Thermal Resistance, Junction to Ambient	20									$^\circ\text{C/W}$

## Electrical Characteristics

$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Device									Units
		5400	5401	5402	5403	5404	5405	5406	5407	5408	
$V_F$	Forward Voltage @ 3.0 A										V
$I_{rr}$	Maximum Full Load Reverse Current, Full Cycle $T_A = 105^\circ\text{C}$										mA
$I_R$	Reverse Current @ rated $V_R$ $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$										uA
$C_T$	Total Capacitance $V_R = 4.0 \text{ V}, f = 1.0 \text{ MHz}$										pF

### Typical Characteristics

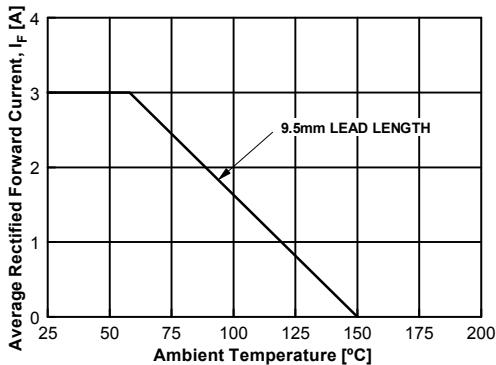


Figure 1. Forward Current Derating Curve

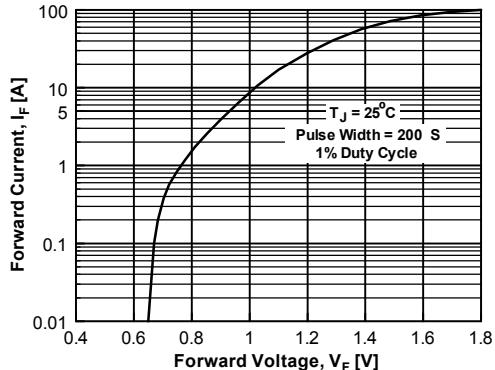


Figure 2. Forward Voltage Characteristics

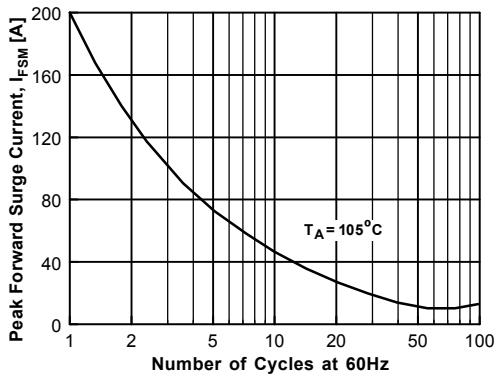


Figure 3. Non-Repetitive Surge Current

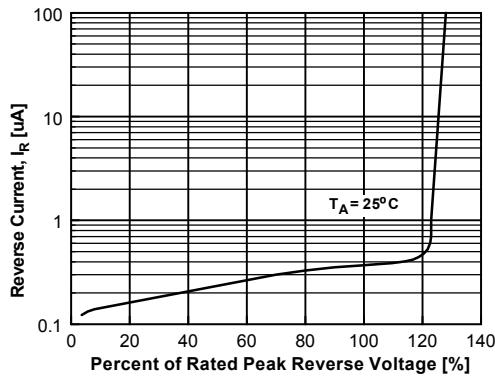


Figure 4. Reverse Current vs Reverse Voltage

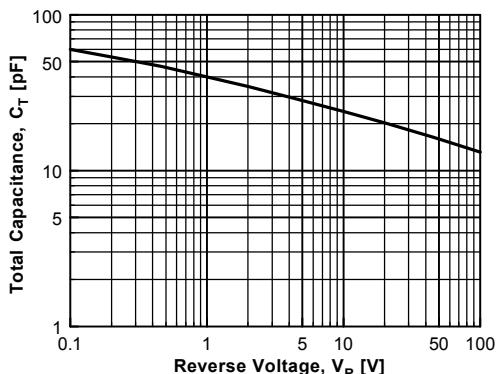


Figure 5. Total Capacitance